Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
Between 0.195 inche	s and 0.350 inches
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.215 inche	s and 0.265 inches
Function For Which	Designed:
Zener diode	
Electrode Internally	-electrically Connected To Case:
Cathode	
Mounting Method:	
Terminal	
Semiconductor Mat	erial:
Silicon	
Voltage Rating In V	olts Per Characteristic:
30.0 regulator voltag	ge
Voltage Tolerance I	n Percent:
-5.0/+5.0	
Current Rating Per	Characteristic:
31.00 milliamperes re	epetitive peak forward current
Power Rating Per C	haracteristic:
1.0 watts small-signa	l input power, common-collector preset
Maximum Operating	g Tempurature Per Measurement Point:
175.0 degrees celsiu	s ambient air
Test Data Documen	t:
81349-mil-s-19500 s	pecification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes cor	nmercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and po	erformance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And	Quantity:
2 uninsulated wire lea	ad
Specification Data:	
81349-mil-s-19500/1	15 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
No	
Fiig:	
- A110a0	